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Stocking Distributor

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Diodes Incorporated DMP2035UTS-13

For any questions, you can email us directly: <u>sales@integrated-circuit.com</u>







DMP2035UTS

DUAL P-CHANNEL ENHANCEMENT MODE MOSFET

Features

- **Dual P-Channel MOSFET**
- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Lead Free By Design/RoHS Compliant (Note 1)
- ESD Protected up to 3kV
- "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

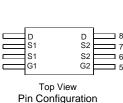
- Case: TSSOP-8L
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Marking Information: See Page 5
- Ordering Information: See Page 5
- Weight: 0.039 grams (approximate)

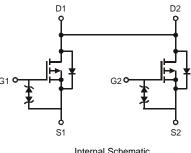






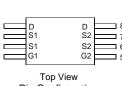


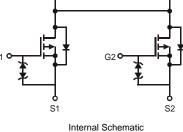




TOP VIEW

BOTTOM VIEW





Maximum Ratings @T_A = 25°C unless otherwise specified

Characte	eristic		Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	-20	V
Gate-Source Voltage			V _{GSS}	±8	V
Continuous Drain Current (Note 3)	Steady State	T _A = 25°C T _A = 85°C	ID	6.04 3.96	А
Pulsed Drain Current (Note 4)			I _{DM}	22	A

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 3)	PD	0.89	W
Thermal Resistance, Junction to Ambient @T _A = 25°C	R _{θJA}	142.7	°C/W
Operating and Storage Temperature Range	TJ, T _{STG}	-55 to +150	C°

Notes: 1. No purposefully added lead.

Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
Device mounted on FR-4 substrate PC board with minimum recommended pad layout.

4. Repetitive rating, pulse width limited by junction temperature.



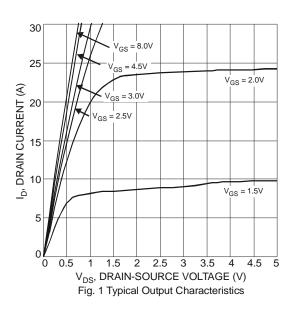


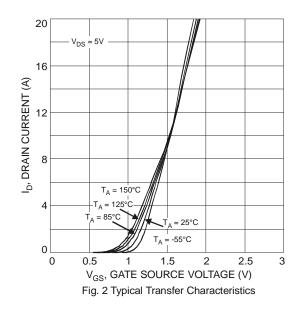
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Electrical Characteristics @T _A = 25°C unless otherwise specified							
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 5)							
Drain-Source Breakdown Voltage	BV _{DSS}	-20	-	-	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	-	-	-1.0	μA	$V_{DS} = -20V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	-	-	±10	μΑ	$V_{GS} = \pm 8V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 5)							
Gate Threshold Voltage	V _{GS(th)}	-0.4	-0.7	-1.0	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$	
			23 30	35 45 62	mΩ	$V_{GS} = -4.5V, I_D = -4.0A$	
Static Drain-Source On-Resistance	R _{DS (ON)}	-				$V_{GS} = -2.5V, I_D = -4.0A$	
			41			V _{GS} = -1.8V, I _D = -2.0A	
Forward Transfer Admittance	Y _{fs}	-	14	-	S	$V_{DS} = -5V, I_D = -4A$	
Diodes Forward Voltage	V _{SD}	-	-0.7	-1.0	V	$Is = -1A, V_{GS} = 0V$	
DYNAMIC CHARACTERISTICS (Note 6)							
Input Capacitance	C _{iss}	-	1610	-	pF		
Output Capacitance	C _{oss}	-	157	-	pF	$V_{DS} = -10V, V_{GS} = 0V,$ f = 1.0MHz	
Reverse Transfer Capacitance	Crss	-	145	-	pF		
Gate Resistance	Rq	-	9.45	-	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
SWITCHING CHARACTERISTICS							
Total Gate Charge	Qg	-	15.4	-	nC	V _{GS} = -4.5V, V _{DS} = -10V, I _D = -4A	
Gate-Source Charge	Q _{qs}	-	2.5	-	nC		
Gate-Drain Charge	Q _{ad}	-	3.3	-	nC		
Turn-On Delay Time	t _{D(on)}	-	16.8	-	ns		
Turn-On Rise Time	tr	-	12.4	-	ns	$V_{DS} = -10V, V_{GS} = -4.5V,$	
Turn-Off Delay Time	t _{D(off)}	-	94.1	-	ns	$R_{L} = 10\Omega, R_{G} = 6.0\Omega, I_{D} = -1A$	
Turn-Off Fall Time	t _f	-	42.4	-	ns		

Notes: 5. Short duration pulse test used to minimize self-heating effects.

6. Guaranteed by design. Not subject to production testing.



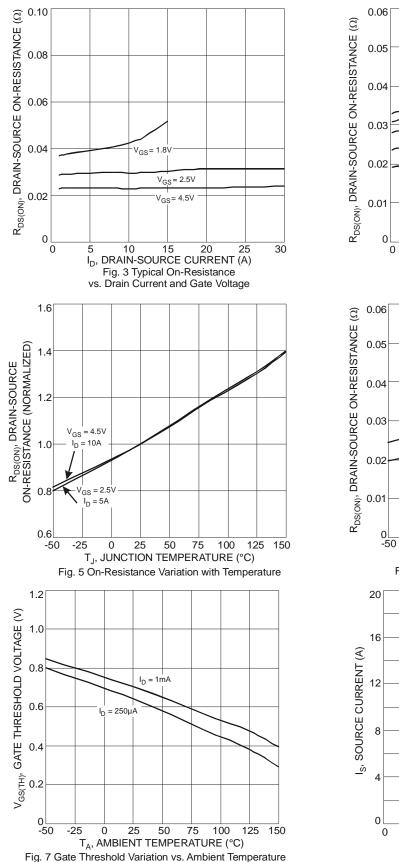




NEW PRODUCT

Distributor of Diodes Incorporated: Excellent Integrated System Limited Datasheet of DMP2035UTS-13 - MOSFET 2P-CH 20V 6.04A 8TSSOP Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

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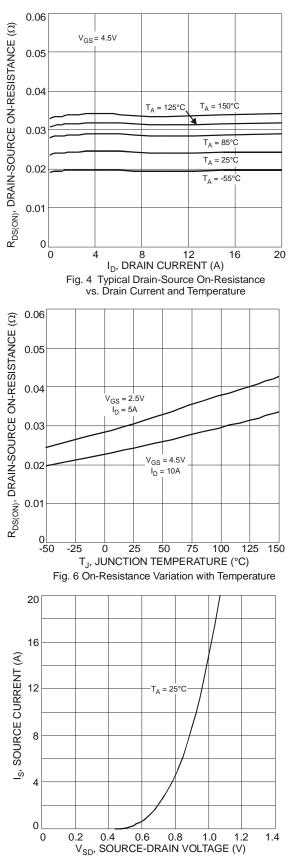


Fig. 8 Diode Forward Voltage vs. Current

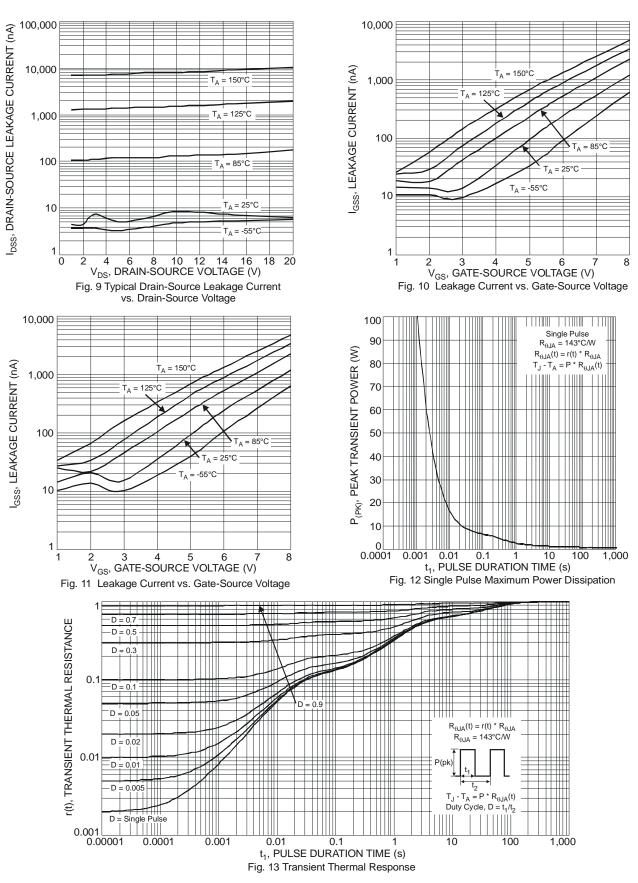
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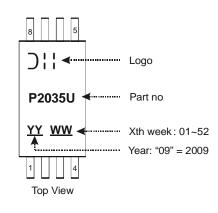
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Ordering Information (Note 7)

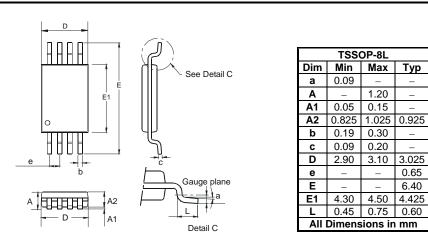
Part Number	Case	Packaging
DMP2035UTS-13	TSSOP-8L	2500 / Tape & Reel
DIVIT 2030018-13	10001-0E	

Notes: 7. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

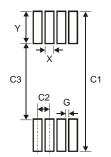
Marking Information



Package Outline Dimensions



Suggested Pad Layout



Dimensions	Value (in mm)
Х	0.45
Y	1.78
C1	7.72
C2	0.65
C3	4.16
G	0.20

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